

# PT60QHx45

# **Pulse Power Thyristor Switch**

DS5267-3 September 2016 (LN33847)

#### **FEATURES**

- Double Side Cooling
- Fast turn-on
- Low Turn-on Losses

### **APPLICATIONS**

- Pulse Power
- Crowbars
- Ignitron replacement

### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>RRM</sub> V	Conditions
PT60QHx45	4500/16	$\begin{split} T_{vj} &= 0^{\circ}\text{C to } 125^{\circ}\text{C}, \\ I_{DRM} &= I_{RRM} = 100\text{mA}, \\ V_{DRM}, V_{RRM} \ t_p &= 10\text{ms}, \end{split}$

Lower voltage grades available.

### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

### PT60QHx45

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

### **KEY PARAMETERS**

$V_{DRM}$	4500V
I <sub>T(AV)</sub>	1000A
I <sub>TSM</sub>	22500A
dl/dt	10000A/µs

\* Higher dV/dt selections available

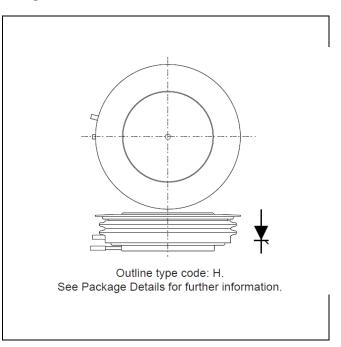


Fig. 1 Package outline

# **CURRENT RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load, T <sub>case</sub> = 80°C	1000	А
I <sub>T(RMS)</sub>	RMS value	-	1570	Α

### **SURGE RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	17.8	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 50\% \ V_{RRM}$	1.58	MA <sup>2</sup> s
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	22.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	2.53	MA <sup>2</sup> s

# THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	s	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.013	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Clamping force 18kN	Double side	-	0.003	°C/W
		Blocking V <sub>DRM</sub> / V <sub>RRM</sub>			125	°C
T <sub>vj</sub> Virtual junction temperature		On-state ( conducting)		-	135	°C
T <sub>stg</sub>	Storage temperature range			-55	125	°C
F <sub>m</sub>	Clamping force			18	22	kN

# **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditio	ns	Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		-	100	mA
dV/dt	Max. linear rate of rise of off-state voltage To 67% $V_{DRM}$ , $T_j = 125$ °C, $R_{gk} \le 1.5\Omega$		-	175	V/µs	
dI/dt	Rate of rise of on-state current	From 67% $V_{DRM}$ to 20kA Gate source 30A $t_r < 1.5 \mu s, T_j = 125 ^{\circ} C$	Non-repetitive	-	10000	A/μs
V <sub>T(TO)</sub>	Threshold voltage	T <sub>vj</sub> = 125°C		-	1.5	V
r <sub>T</sub>	On-state slope resistance – Low level	T <sub>case</sub> = 125°C		-	0.67	mΩ

# **GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Тур.	Max.	Units
$V_{GT}$	Gate trigger voltage	$V_{DRM} = 5V$ , $T_{case} = 25$ °C	-	1.0	V
I <sub>GT</sub>	Gate trigger current	V <sub>DRM</sub> = 5V, T <sub>case</sub> = 25°C	-	3	А

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### **CURVES**

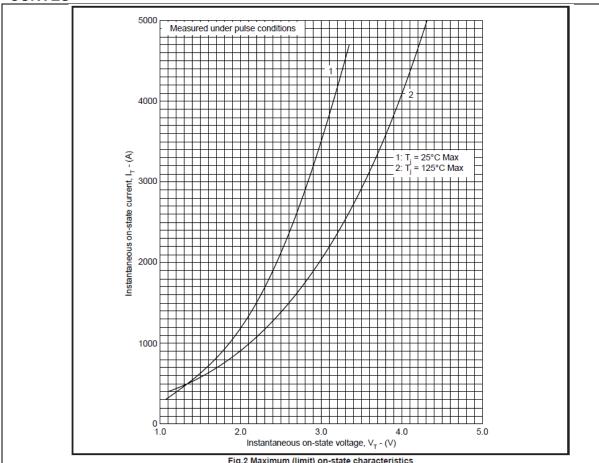


Fig.2 Maximum (limit) on-state characteristics

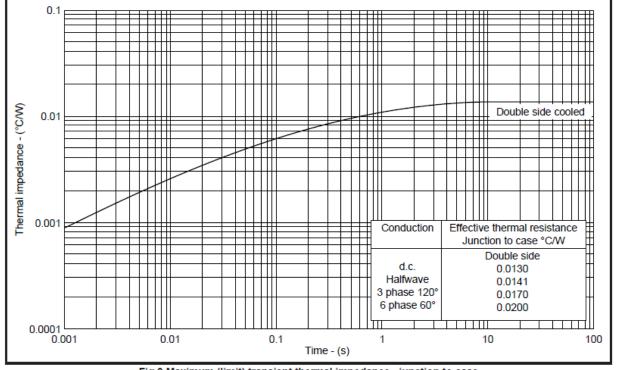


Fig.3 Maximum (limit) transient thermal impedance - junction to case

### ORDERING INFORMATION

PT Pulse Power Thyristor 40Q Device type

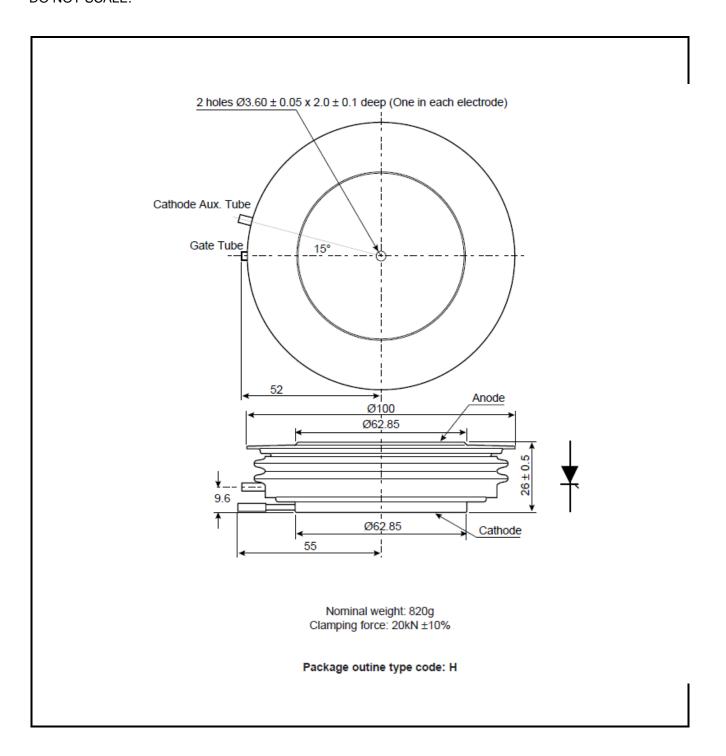
P Package outline type code x lead length (see table, right) 45 Voltage x100

Lead length (x)				
О	No lead			
С	8"	200mm		
D	10"	250mm		
E	12"	300mm		
F	16"	400mm		
G	18"	450mm		
Н	20"	500mm		
J	24"	600mm		
K	30"	750mm		
L	40"	1000mm		

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### **PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



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